

MOS FIELD EFFECT TRANSISTOR NP88N055ELE, NP88N055KLE NP88N055CLE, NP88N055DLE, NP88N055MLE, NP88N055NLE

SWITCHING N-CHANNEL POWER MOS FET

DATA SHEET

DESCRIPTION

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

<R> ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
NP88N055ELE-E1-AY Note1, 2				
NP88N055ELE-E2-AY Note1, 2			TO-263 (MP-25ZJ) typ. 1.4 g	
NP88N055KLE-E1-AY Note1	Pure Sn (Tin)	Tape 800 p/reel		
NP88N055KLE-E2-AY Note1			TO-263 (MP-25ZK) typ. 1.5 g	
NP88N055CLE-S12-AZ Note1, 2	Sn-Ag-Cu		TO-220 (MP-25) typ. 1.9 g	
NP88N055DLE-S12-AY Note1, 2		Tube 50 a /baba	TO-262 (MP-25 Fin Cut) typ. 1.8 g	
NP88N055MLE-S18-AY Note1	Pure Sn (Tin)	Tube 50 p/tube	TO-220 (MP-25K) typ. 1.9 g	
NP88N055NLE-S18-AY Note1			TO-262 (MP-25SK) typ. 1.8 g	

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Not for new design

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance

 $R_{\text{DS(on)1}}$ = 5.2 m $\Omega\,$ MAX. (VGs = 10 V, ID = 44 A)

 $R_{\text{DS(on)2}}$ = 6.3 m $\Omega\,$ MAX. (VGs = 5.0 V, ID = 44 A)

 $R_{\text{DS(on)3}}$ = 6.8 m $\Omega\,$ MAX. (VGs = 4.5 V, ID = 44 A)

- Low input capacitance
- Ciss = 9700 pF TYP.
- Built-in gate protection diode

(TO-220)







(TO-263)



The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

Document No. D13933EJ7V0DS00 (7th edition) Date Published October 2007 NS Printed in Japan

© NEC Electronics Corporation 1999, 2000, 2007

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	55	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C) ^{Note1}	ID(DC)	±88	А
Drain Current (pulse) ^{Note2}	D(pulse)	±352	А
Total Power Dissipation (T _A = 25°C)	Рт	1.8	W
Total Power Dissipation (Tc = 25° C)	Рт	288	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Current ^{Note3}	las	75/88	А
Single Avalanche Energy ^{Note3}	Eas	562/232	mJ

Notes 1. Calculated constant current according to MAX. allowable channel temperature.

- **2.** PW \leq 10 μ s, Duty cycle \leq 1%
- 3. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V (see Figure 4.)

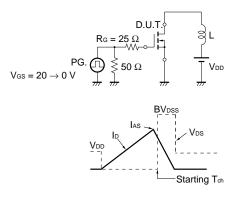
THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	0.52	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

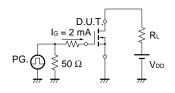
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 55 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Forward Transfer Admittance	y fs	V _{DS} = 10 V, I _D = 44 A	38	75		S
Drain to Source On-state Resistance	RDS(on)1	V _{GS} = 10 V, I _D = 44 A		4.1	5.2	mΩ
	RDS(on)2	V _{GS} = 5.0 V, I _D = 44 A		4.8	6.3	mΩ
	RDS(on)3	V _{GS} = 4.5 V, I _D = 44 A		5.1	6.8	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V,		9700	14600	pF
Output Capacitance	Coss	$V_{GS} = 0 V$,		1100	1700	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		490	890	pF
Turn-on Delay Time	td(on)	V _{DD} = 28 V, I _D = 44 A,		37	82	ns
Rise Time	tr	V _{GS} = 10 V,		22	56	ns
Turn-off Delay Time	td(off)	R _G = 1 Ω		180	360	ns
Fall Time	tr			35	88	ns
Total Gate Charge	Q _{G1}	V_{DD} = 44 V, V_{GS} = 10 V, I_D = 88 A		160	240	nC
	Q _{G2}	V _{DD} = 44 V,		88	140	nC
Gate to Source Charge	Q _{GS}	V _{GS} = 5.0 V,		27		nC
Gate to Drain Charge	Qgd	ID = 88 A		48		nC
Body Diode Forward Voltage	VF(S-D)	IF = 88 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 88 A, VGS = 0 V,		62		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		120		nC

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

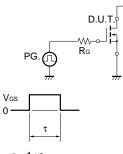
TEST CIRCUIT 1 AVALANCHE CAPABILITY



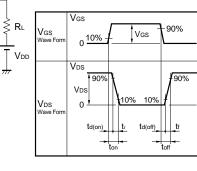
TEST CIRCUIT 3 GATE CHARGE



TEST CIRCUIT 2 SWITCHING TIME

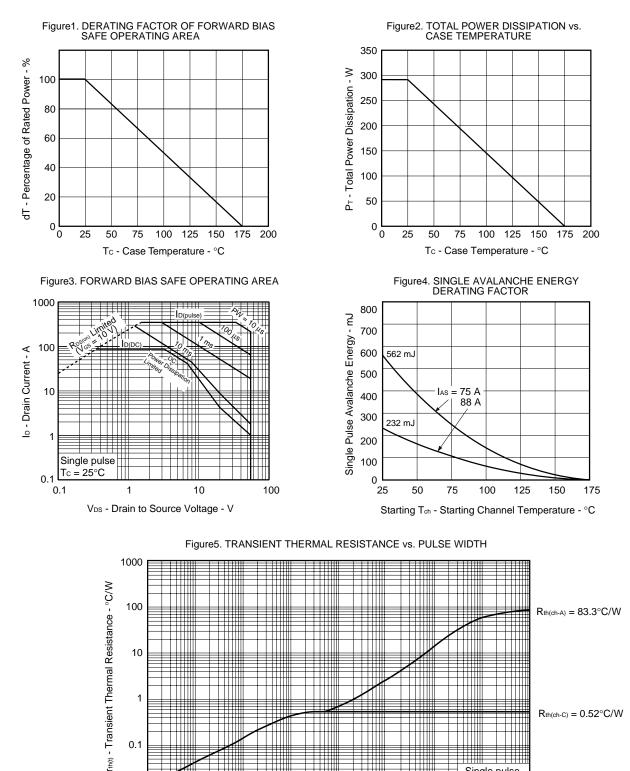


 $\tau = 1 \,\mu s$ Duty Cycle $\leq 1\%$



NEC

TYPICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$



100 m

PW - Pulse Width - s

1

10

1000

1111 Single pulse

 $Tc = 25^{\circ}C$

100

Ш

10 m

1 m

0.1

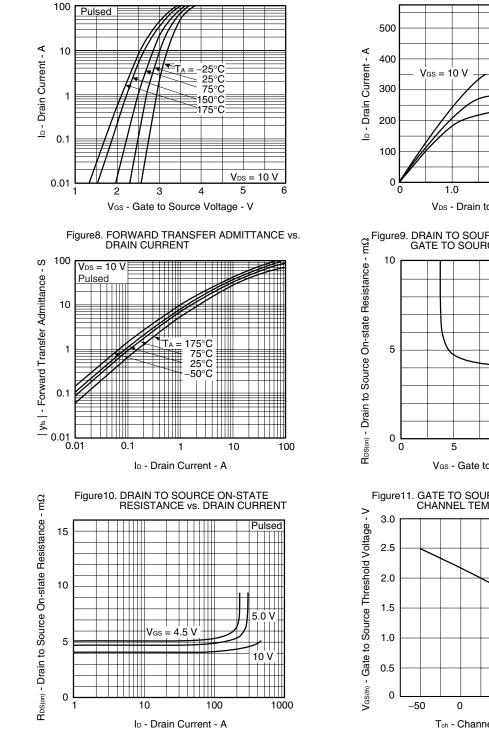
0.01

10 *µ*

100 *µ*

NEC

Figure6. FORWARD TRANSFER CHARACTERISTICS



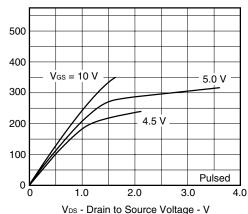


Figure7. DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

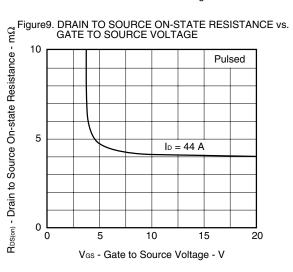
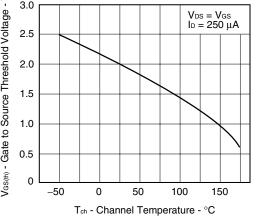
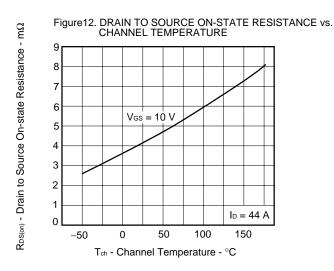


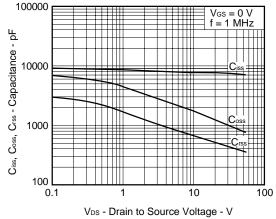
Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

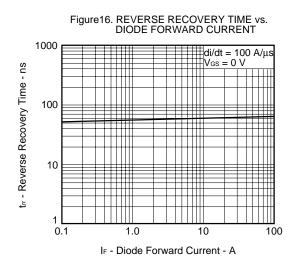


NEC









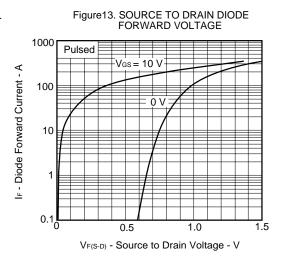


Figure15. SWITCHING CHARACTERISTICS

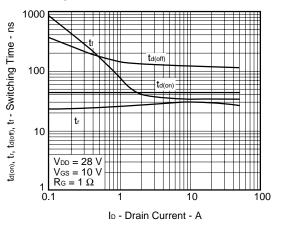
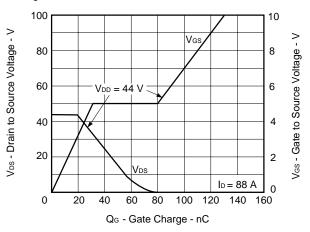
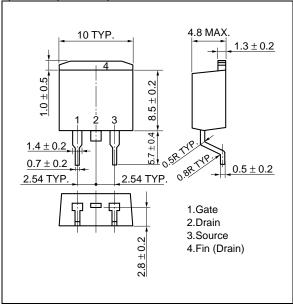


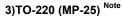
Figure17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS

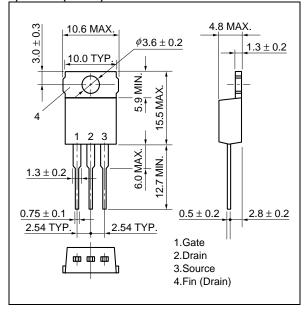


<R> PACKAGE DRAWINGS (Unit: mm)

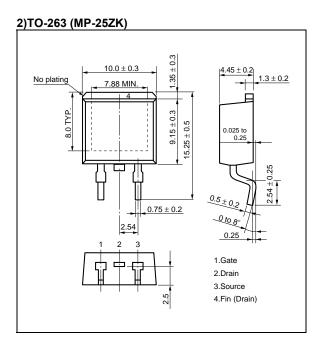




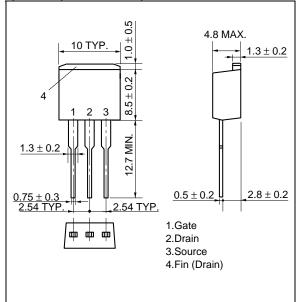




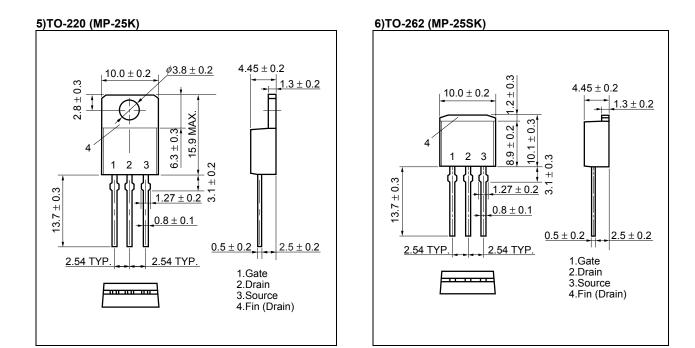
Note Not for new design



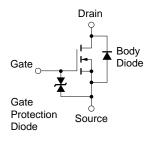
4)TO-262 (MP-25 Fin Cut) Note







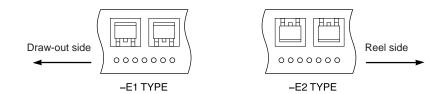
EQUIVALENT CIRCUIT



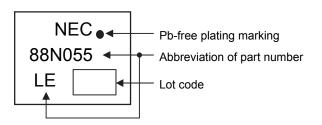
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

<R> TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



<R> MARKING INFORMATION



<R> RECOMMENDED SOLDERING CONDITIONS

These products should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol	
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below		
MP-25ZJ, MP-25ZK	Time at maximum temperature: 10 seconds or less		
	Time of temperature higher than 220°C: 60 seconds or less		
	Preheating time at 160 to 180°C: 60 to 120 seconds	IR60-00-3	
	Maximum number of reflow processes: 3 times		
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less		
Wave soldering	Maximum temperature (Solder temperature): 260°C or below		
MP-25, MP-25K, MP-25SK,	Time: 10 seconds or less	THDWS	
MP-25 Fin Cut	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 350°C or below		
MP-25ZJ, MP-25ZK,	Time (per side of the device): 3 seconds or less	P350	
MP-25K, MP-25SK	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 300°C or below		
MP-25, MP-25 Fin Cut	Time (per side of the device): 3 seconds or less	P300	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		

Caution Do not use different soldering methods together (except for partial heating).

• The information in this document is current as of October, 2007. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

- No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of a customer's equipment shall be done under the full responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customerdesignated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).